

IGBT Module

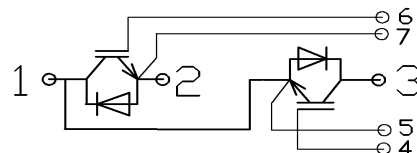
Features

- 1200V 100A, $V_{CE(sat)}(typ.) = 2.1 V@100A$
- Ultrafast switching speed
- Excellent short circuit ruggedness
- 34mm half bridge module



Mechanical Data

- **Case:** D1 (34mm)(plastic package).
Lead free; RoHS compliant
- **Molding Compound Flammability Rating:**
UL 94 V-0



Benefits

- Inverter for motor drive
- AC and DC servo drive amplifier
- Excellent Current Sharing in Parallel Operation

Applications

CREATEK's IGBTs offer ultrafast switching speed for application such as welding, inductive-heating, UPS and other high frequency applications

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
V_{CES}	Collector-Emitter Voltage	1200	V
V_{GES}	Gate-Emitter Voltage	± 30	V
I_C	Continuous Collector Current ($T_C=25^{\circ}C$)	200	A
	Continuous Collector Current ($T_C=100^{\circ}C$)	100	A
I_{CM}	Pulsed Collector Current (Note 1)	400	A
I_F	Diode Continuous Forward Current ($T_C=100^{\circ}C$)	100	A
I_{FM}	Diode Maximum Forward Current (Note 1)	400	A
t_{sc}	Short Circuit Withstand Time	10	μs
$t_{sc (Max)}$	Maximum Short Circuit Withstand Time	>40	μs
I_{sc}	Short Circuit Current	890	A
P_D	Maximum Power Dissipation ($T_C=25^{\circ}C$)	1500	W
	Maximum Power Dissipation ($T_C=100^{\circ}C$)	700	W
T_J	Operating Junction Temperature Range	-55 to +150	$^{\circ}C$
T_{STG}	Storage Temperature Range	-55 to +150	$^{\circ}C$

Thermal Characteristics

Symbol	Parameter	Max.	Units
$R_{th j-c}$	Thermal Resistance, Junction to case for IGBT	0.18	$^{\circ}C/W$
$R_{th j-c}$	Thermal Resistance, Junction to case for Diode	0.30	$^{\circ}C/W$
Weight	Weight of Module	150	g

Electrical Characteristics (T_C=25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV _{CES}	Collector-Emitter Breakdown Voltage	V _{GE} =0V, I _C = 250μA	1200	-	-	V
I _{CES}	Collector-Emitter Leakage Current	V _{CE} = 1200V, V _{GE} =0V	-	-	250	μA
I _{GES}	Gate Leakage Current, Forward	V _{GE} =30V, V _{CE} =0V	-	-	100	nA
	Gate Leakage Current, Reverse	V _{GE} = -30V, V _{CE} =0V	-	-	-100	nA
V _{GE(th)}	Gate Threshold Voltage	V _{GE} =V _{CE} , I _C =250μA	4.5	-	5.7	V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	V _{GE} =15V, I _C =100A	-	2.1	2.4	V
t _{d(on)}	Turn-on Delay Time	V _{CC} =600V V _{GE} =± 15V I _C =100A R _G =10Ω Inductive Load T _C =25°C	-	290	-	ns
t _r	Turn-on Rise Time		-	106	-	ns
t _{d(off)}	Turn-off Delay Time		-	760	-	ns
t _f	Turn-off Fall Time		-	124	-	ns
E _{on}	Turn-on Switching Loss		-	12.30	-	mJ
E _{off}	Turn-off Switching Loss		-	4.60	-	mJ
E _{ts}	Total Switching Loss		-	16.90	-	mJ
C _{ies}	Input Capacitance	V _{CE} =25V	-	8200	-	pF
C _{oes}	Output Capacitance	V _{GE} =0V	-	1100	-	pF
C _{res}	Reverse Transfer Capacitance	f = 1MHz	-	650	-	pF
R _{Gint}	Integrated gate resistor	f=1M; V _{pp} =1V		3.5		Ω

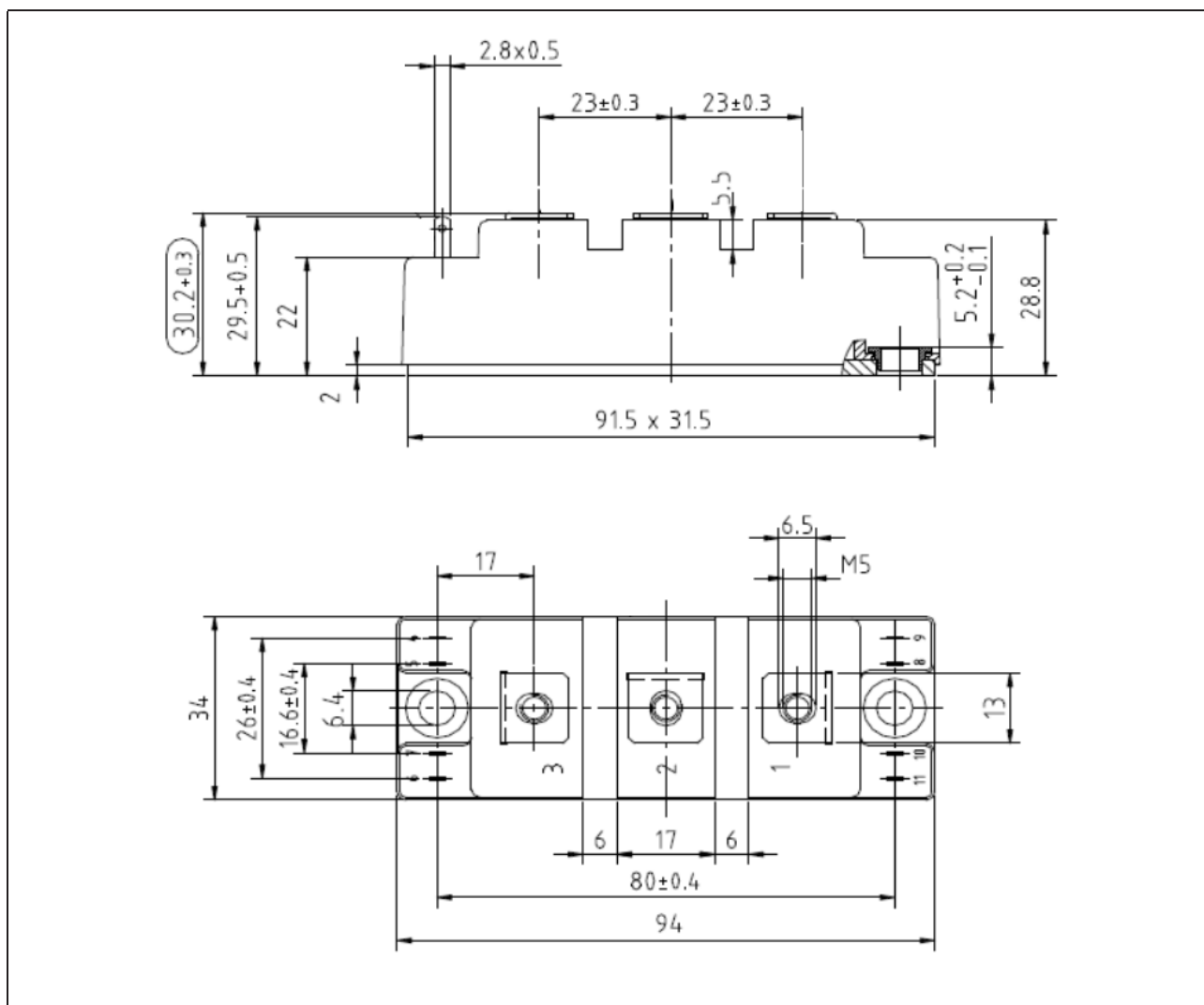
Electrical Characteristics of Diode (T_C=25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
V _F	Diode Forward Voltage	I _F =100A	-	1.9		V
t _{rr}	Diode Reverse Recovery Time	V _{CE} = 600V	-	155		ns
I _{rr}	Diode peak Reverse Recovery Current	I _F = 100A	-	71		A
Q _{rr}	Diode Reverse Recovery Charge	dI _F /dt = 500A/us	-	5930		nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature

Package Dimensions(mm)



Ordering information

Order code	Package	Packaging option	Base quantity	Packaging specification
GPk100HF120D1	D1(32mm)	BOX	16pcs /BOX	

Revision history

Date	Revision	Changes
23-May-2012	1.0	Initial release

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